

Expand your device characterization with Ultra-Fast I-V testing

PULSE AND TRANSIENT I-V, SOI CMOS, FLASH, PHASE CHANGE MEMORY, LDMOS, HI-K, NBTI/PBTI

To characterize a semiconductor device, material, or process technology completely, you need to be able to make precision DC I-V, AC impedance, and ultra-fast or transient I-V measurements. The latest upgrades to the Model 4200 characterization system deliver ultra-fast voltage waveform generation and measurement capabilities that make





WHAT DOES ULTRA-FAST I-V OFFER YOUR CHARACTERIZATION LAB THAT OTHER SOLUTIONS DON'T?

FEATURE	BENEFIT
The broadest dynamic measurement ranges available in the semiconductor test industry	You can characterize a full range of material, device, and process technologies with a single set of instrumentation.
Extensive sample libraries	You can acquire and analyze data quickly and easily.
Modern graphical interface that combines control for precision DC, C-V and ultra-fast pulse and I-V instrumentation	You can integrate all three types of tests into a single test sequence from the same easy-to-use interface.
Optional multi-measurement performance cables (MMPC)	You'll eliminate the need for complex and time-consuming re-cabling during testing
Compatibility with both new and existing Model 4200 systems	You can expand your system readily to address new characterization challenges.







Current measurements vs. time comparison of Keithley DC I-V and Ultra-Fast I-V instruments

ONGOING SYSTEM ENHANCEMENTS ENSURE ONGOING ROI SUPPORT FOR EMERGING MATERIAL, DEVICE, AND

The Model 4200-SCS offers the semiconductor industry the broadest and deepest applications coverage of any parameter analyzer on the market. Keithley has continually enhanced the Model 4200-SCS's hardware and software ever since its introduction. Our commitment to ongoing system innovation assures you of a cost-effective upgrade path, so you'll never have to buy a new parametric analyzer because your old one can't adapt to new test requirements. The Model 4200-SCS is engineered to keep up with the industry's changing test needs, stretching your capital investment further and improving your return on your equipment investment.

For more details on Ultra-Fast I-V applications, download the Ultra-Fast I-V Applications Overview at http://www.keithley.com/data?asset=52837

SUPPORT FOR EMERGING MATERIAL, DEVICE, AND PROCESS CHARACTERIZATION CHALLENGES LIKE THESE:

- Ultra-fast general-purpose I-V measurements
- Pulsed I-V and transient I-V measurements
- Flash, PCRAM, and other non-volatile memory tests
- Isothermal testing of mediumsized power devices
- Materials testing for scaled CMOS, such as high-κ dielectrics
- Ultra-fast NBTI/PBTI reliability tests

- Single-pulse charge trapping (SPCT)
- Charge-based capacitance measurement (CBCM)
- Silicon-On-Insulator
- LDMOS/GaAs isothermal
- Charge pumping
- Thermal impedance
- MEMs cap
- RTS CMOS

To learn more about how the latest Model 4200-SCS upgrade can expand your materials, device, and process characterization capabilities, contact your local Keithley Instruments representative to arrange a consultation. Contact information is available at www.keithley.com

